TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX14F,TC74LVX14FN,TC74LVX14FT

Hex Schmitt Inverter

Note: xxxFN (JEDEC SOP) is not available in Japan.

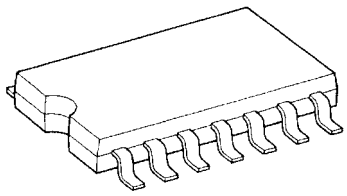
The TC74LVX14F/ FN/ FT is a high-speed CMOS HEX SCHMITT INVERTER fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

Pin configuration and function are the same as the TC74LVX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74LVX14 can be used as a line receivers which will receive slow input signals.

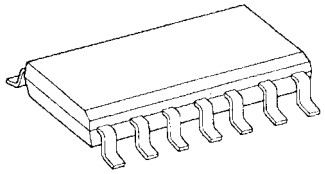
An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

TC74LVX14F



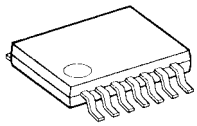
SOP14-P-300-1.27

TC74LVX14FN



SOL14-P-150-1.27

TC74LVX14FT



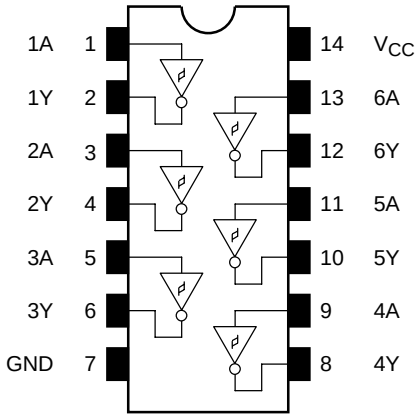
TSSOP14-P-0044-0.65

Weight
SOP14-P-300-1.27: 0.18 g (typ.)
SOL14-P-150-1.27: 0.12 g (typ.)
TSSOP14-P-0044-0.65: 0.06 g (typ.)

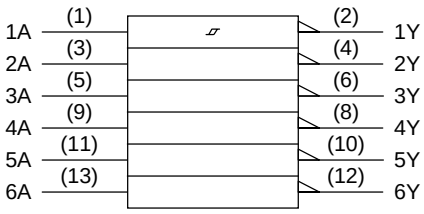
Features

- High-speed: t_{pd} = 6.8 ns (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: I_{CC} = 2 μA (max) (Ta = 25°C)
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Low niose: V_{OLP} = 0.5 V (max)
- Pin and function compatible with 74HC14

Pin Assignment (top view)



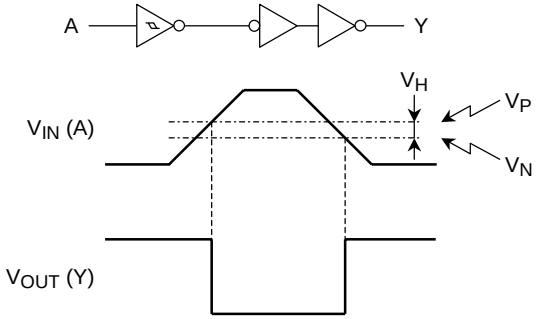
IEC Logic Symbol



Truth Table

Inputs	Outputs
A	Y
L	H
H	L

System Diagram, Waveform



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
				V_{CC} (V)	Min	Typ.	Max	Min	Max	
Threshold voltage	H-level	V_P	—	3.0	—	—	2.2	—	2.2	V
	L-level	V_N	—	3.0	0.9	—	—	0.9	—	
Hysteresis voltage		V_H	—	3.0	0.3	—	1.2	0.3	1.2	V
Output voltage	H-level	V_{OH}	V_{IN} = V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				I_{OH} = −50 μA	3.0	2.9	3.0	—	2.9	—	
				I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
	L-level	V_{OL}	V_{IN} = V_{IH}	I_{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA	3.0	—	0	0.1	—	0.1	
				I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		3.6	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	2.0	—	20.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH}	—	2.7	15	—	8.7	16.3	1.0	19.5	ns
				50	—	11.2	19.8	1.0	23.0	
	t_{pHL}		3.3 ± 0.3	15	—	6.8	10.6	1.0	12.5	
				50	—	9.3	14.1	1.0	16.0	
Output to output skew	t_{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t_{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C_{IN}	(Note 2)			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note 3)			—	21	—	—	—	pF

Note 1: Parameter guaranteed by design.
($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

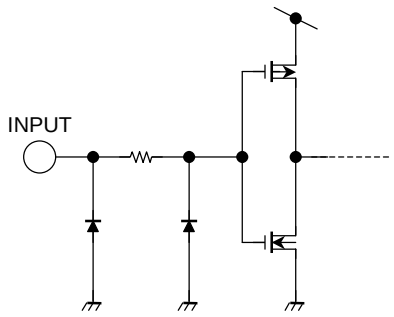
Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

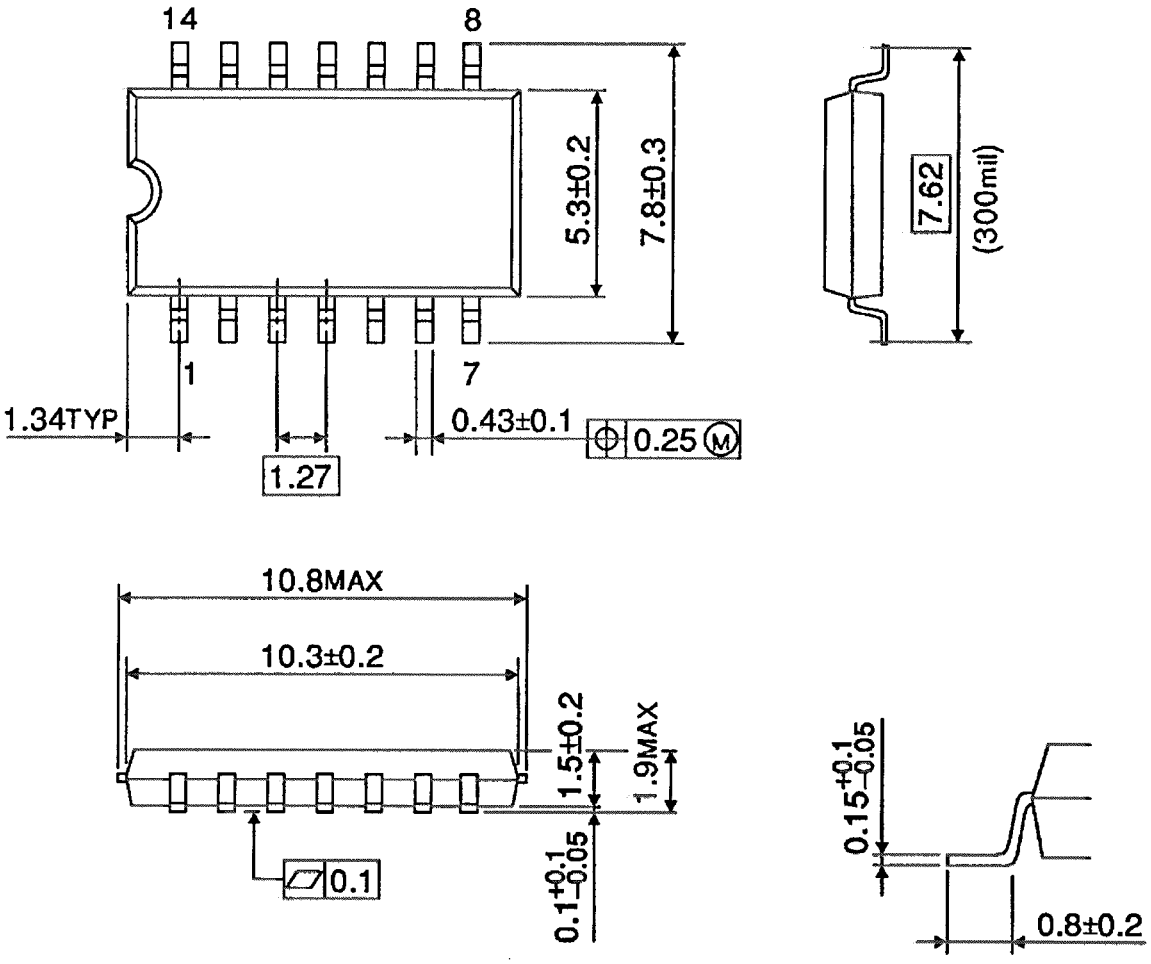
Characteristics		Symbol	Test Condition	V_{CC} (V)	Typ.	Limit	Unit
Quiet output maximum dynamic	V_{OL}	V_{OLP}	—	3.3	0.3	0.5	V
Quiet output minimum dynamic	V_{OL}	V_{OLV}	—	3.3	−0.3	−0.5	V
Minimum high level dynamic input voltage	V_{IH}	V_{IHD}	—	3.3	—	2.2	V
Maximum low level dynamic input voltage	V_{IL}	V_{ILD}	—	3.3	—	0.9	V

Input Equivalent Circuit



Package Dimensions

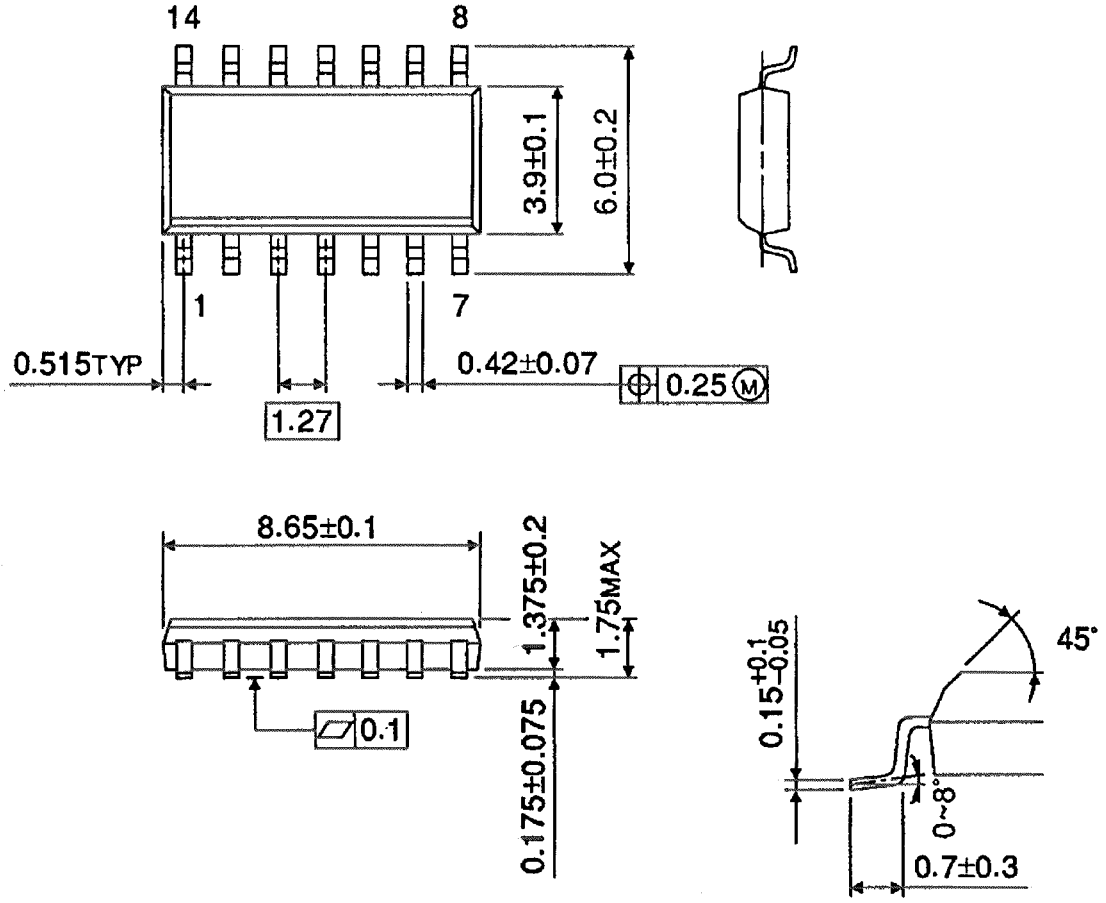
SOP14-P-300-1.27 Unit : mm



Weight: 0.18 g (typ.)

Package Dimensions

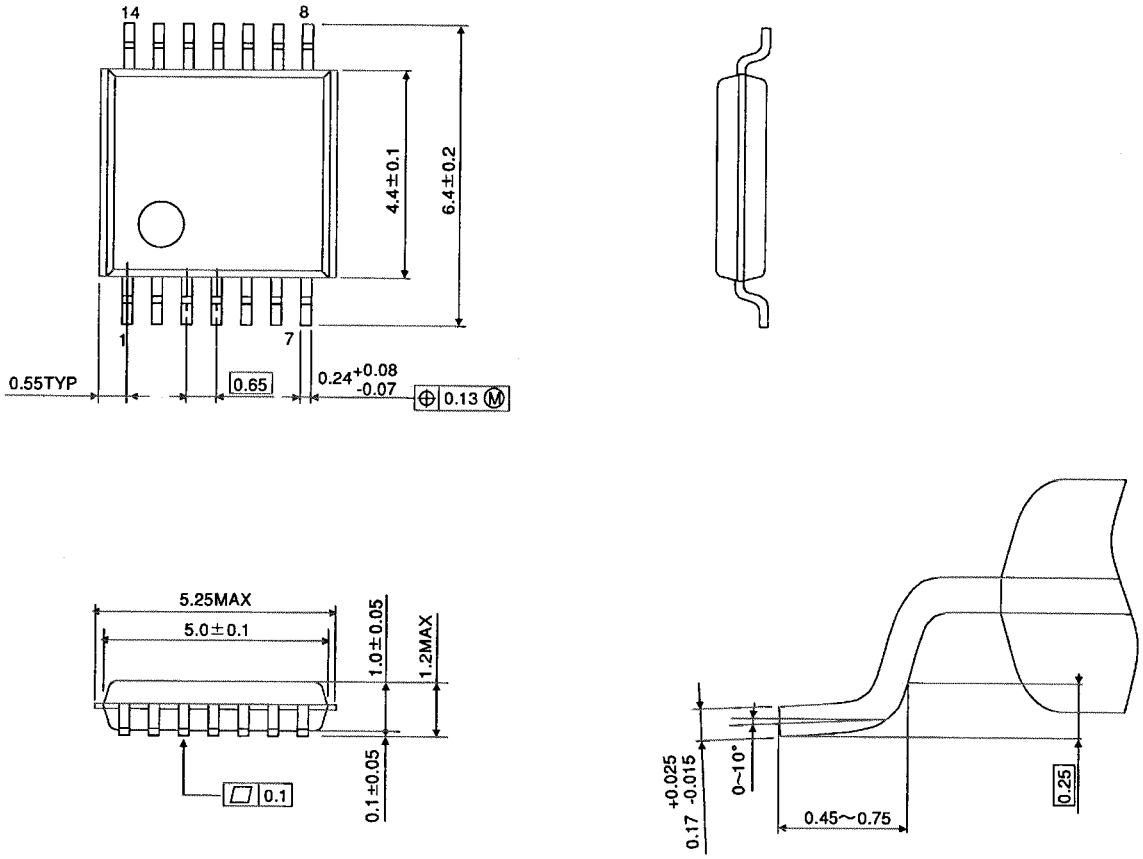
SOL14-P-150-1.27 Unit : mm



Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65 Unit : mm



Weight: 0.06 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the “Handling Guide for Semiconductor Devices,” or “TOSHIBA Semiconductor Reliability Handbook” etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer’s own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.